

BFR843EL3E6327XTSA1 Information


For Reference Only

Part Number [BFR843EL3E6327XTSA1](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - Bipolar \(BJT\) - RF](#)
Description TRANSISTOR NPN TSLP-3
Package 3-XDFDN
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


BFR843EL3E6327XTSA1 Specifications

Manufacturer Part Number	BFR843EL3E6327XTSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
Package	3-XDFDN
Series	*
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	2.6V
Frequency - Transition	-
Noise Figure (dB Typ @ f)	-
Gain	25.5dB
Power - Max	125mW
DC Current Gain (hFE) (Min) @ Ic, Vce	-
Current - Collector (Ic) (Max)	55mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	3-XDFDN
Supplier Device Package	TSLP-3-10

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BFR843EL3E6327XTSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BFR843EL3E6327XTSA1 Payment Methods



BFR843EL3E6327XTSA1 Shipping Methods



If you have any question about BFR843EL3E6327XTSA1, please do not hesitate to contact us!

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